

BS 3-9-01
Pres/Jan/AB

PATENT

Docket No.: 49657-904

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Yoshinori TANAKA, et al.

Serial No.:

(Divisional of Serial No. 09/095,612)

Group Art Unit:

Filed: January 10, 2001

Examiner:

For: SEMICONDUCTOR DEVICE COMPRISING CAPACITOR AND METHOD OF
FABRICATING THE SAME

PRELIMINARY AMENDMENT

Commissioner for Patents
Washington, DC 20231

Sir:

Prior to examination of the above-referenced application, please amend the application as follows:

IN THE CLAIMS:

Please add new claims 21 through 24 as follows:

(B)

--21. The semiconductor device in accordance with claim 12, wherein

said part of said insulating film having a width being smaller than the minimum working size formable by photolithography.

22. The semiconductor device in accordance with claim 21, wherein

a side surface of said capacitor lower electrode has a curved plane.

23. The semiconductor device in accordance with claim 21, wherein

said insulating film includes an upper insulating film and a lower insulating film being